IN THE CLAIMS:

Please CANCEL claims 17-29 and 31 without prejudice to or disclaimer of the recited subject matter.

Please AMEND claim 30, and ADD new claims 33-44, as follows. For the Examiner's convenience, all claims currently pending have been reproduced below.

1-29. (Canceled)

30. (Currently Amended) An exposure apparatus for exposing a substrate to a pattern, said apparatus detecting a position of a target mark out of a plurality of marks, disposed with respect to each shot in a region of the substrate to obtain a position of the region of the substrate a shot, said apparatus comprising:

a stage configured to mount the substrate and to move be moved;

a scope configured to sense a first an image of the substrate at a first magnification and a second an image of the substrate at a second magnification higher than the first magnification;

a processor configured to extract, from the first an image sensed by said scope at the first magnification, a position of a first mark out of the plurality of marks and a feature of a region outside the first mark, to identify the first mark based on the extracted feature, to extract, from the second an image sensed by said scope at the second magnification, a position of the target mark, to evaluate reliability of the extracted position of the target mark, to select a second mark, different from instead of the target mark, from the plurality of marks as a new target mark based on the evaluated reliability and the identified first mark, in order if the evaluated reliability

is less than a threshold, and to extract a position of the selected second mark from an image sensed by said scope at the second magnification; and

a controller configured to control a position of said stage based on the extracted position of the second mark.

31. (Canceled)

32. (Previously Presented) A method of detecting a position of a target mark out of a plurality of marks in a region of an object to obtain a position of the region of the object, said method comprising steps of:

sensing a first image of the object at a first magnification;

sensing a second image of the object at a second magnification higher than the first magnification;

extracting, from the first image, a position of a first mark out of the plurality of marks and a feature of a region outside the first mark;

identifying the first mark based on the extracted feature;

extracting, from the second image, a position of the target mark;

evaluating reliability of the extracted position of the target mark;

selecting a second mark, different from the target mark, from the plurality of marks as a new target mark based on the evaluated reliability and the identified first mark; and

extracting a position of the selected second mark from an image sensed at the second magnification.

- 33. (New) An apparatus according to claim 30, wherein the feature corresponds to an auxiliary pattern, which is included in the object and is associated with the first mark.
- 34. (New) An apparatus according to claim 33, wherein the plurality of marks have different auxiliary patterns, respectively.
- 35. (New) An apparatus according to claim 33, wherein the auxiliary pattern is connected to the first mark.
- 36. (New) An apparatus according to claim 33, wherein the auxiliary pattern is surrounded by the first mark.
- 37. (New) An apparatus according to claim 30, wherein the feature corresponds to a position of the first mark relative to another mark out of the plurality of marks.
- 38. (New) An apparatus according to claim 30, wherein the feature corresponds to a position of the first mark relative to plural marks out of the plurality of marks.
- 39. (New) An apparatus according to claim 30, wherein said processor is configured to select the second mark as the new target mark from a plurality of marks, out of the plurality of marks, extracted by said processor from the image that is sensed by said scope at the first magnification.

- 40. (New) An apparatus according to claim 39, wherein said processor is configured to select the second mark as the new target mark based on a contrast of each of the extracted plurality of marks.
- 41. (New) An apparatus according to claim 30, wherein the object is a substrate on which a device is to be formed.
- 42. (New) An apparatus according to claim 41, further comprising a stage configured to mount the substrate and to be moved.
- 43. (New) An apparatus according to claim 42, further comprising a controller configured to control a position of said stage based on the extracted position of the second mark.
- 44. (New) An apparatus according to claim 30, wherein the object is a first substrate on which a device is to be formed, and a mark corresponding to the second mark is initially selected as the target mark with respect to a subsequent substrate in a lot including the first substrate.